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Dated: June 3, 2004 Signature: 
Paul B. Stephens

SLB
Docket No.: 30205/37980A
(PATENT)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:
Seon Y. Cha

Application No.: 10/663,892

Art Unit: 2812

Filed: September 16, 2003

Examiner: J. Jey Tsai

For: Magnetic Random Access Memory Having
Transistor of Vertical Structure with Writing Line
Formed on an Upper Portion of the Magnetic
Tunnel Junction Cell

Please send to [unclear]

AMENDMENT UNDER 37 CFR §1.312

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

INTRODUCTORY COMMENTS

Please amend the above-identified U.S. patent application as follows:

Amendments to the Specification begin on page 2 of this paper.

Remarks begin on page 3 of this paper.